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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	-
Number of Logic Elements/Cells	75264
Total RAM Bits	516096
Number of I/O	620
Number of Gates	3000000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 85°C (TA)
Package / Case	896-BGA
Supplier Device Package	896-FBGA (31x31)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/agle3000v5-fg896i

Reduced Cost of Ownership

Advantages to the designer extend beyond low unit cost, performance, and ease of use. Unlike SRAM-based FPGAs, Flash-based IGLOOe devices allow all functionality to be Instant On; no external boot PROM is required. On-board security mechanisms prevent access to all the programming information and enable secure remote updates of the FPGA logic. Designers can perform secure remote in-system reprogramming to support future design iterations and field upgrades with confidence that valuable intellectual property cannot be compromised or copied. Secure ISP can be performed using the industry-standard AES algorithm. The IGLOOe family device architecture mitigates the need for ASIC migration at higher user volumes. This makes the IGLOOe family a cost-effective ASIC replacement solution, especially for applications in the consumer, networking/communications, computing, and avionics markets.

Firm-Error Immunity

Firm errors occur most commonly when high-energy neutrons, generated in the upper atmosphere, strike a configuration cell of an SRAM FPGA. The energy of the collision can change the state of the configuration cell and thus change the logic, routing, or I/O behavior in an unpredictable way. These errors are impossible to prevent in SRAM FPGAs. The consequence of this type of error can be a complete system failure. Firm errors do not exist in the configuration memory of IGLOOe flash-based FPGAs. Once it is programmed, the flash cell configuration element of IGLOOe FPGAs cannot be altered by high-energy neutrons and is therefore immune to them. Recoverable (or soft) errors occur in the user data SRAM of all FPGA devices. These can easily be mitigated by using error detection and correction (EDAC) circuitry built into the FPGA fabric.

Advanced Flash Technology

The IGLOOe family offers many benefits, including nonvolatility and reprogrammability, through an advanced flash-based, 130-nm LVCMOS process with seven layers of metal. Standard CMOS design techniques are used to implement logic and control functions. The combination of fine granularity, enhanced flexible routing resources, and abundant flash switches allows for very high logic utilization without compromising device routability or performance. Logic functions within the device are interconnected through a four-level routing hierarchy.

IGLOOe family FPGAs utilize design and process techniques to minimize power consumption in all modes of operation.

Advanced Architecture

The proprietary IGLOOe architecture provides granularity comparable to standard-cell ASICs. The IGLOOe device consists of five distinct and programmable architectural features ([Figure 1-1 on page 4](#)):

- Flash*Freeze technology
- FPGA VersaTiles
- Dedicated FlashROM
- Dedicated SRAM/FIFO memory
- Extensive CCCs and PLLs
- Pro I/O structure

The FPGA core consists of a sea of VersaTiles. Each VersaTile can be configured as a three-input logic function, a D-flip-flop (with or without enable), or a latch by programming the appropriate flash switch interconnections. The versatility of the IGLOOe core tile as either a three-input lookup table (LUT) equivalent or a D-flip-flop/latch with enable allows for efficient use of the FPGA fabric. The VersaTile capability is unique to the Microsemi ProASIC® family of third-generation-architecture flash FPGAs. VersaTiles are connected with any of the four levels of routing hierarchy. Flash switches are distributed throughout the device to provide nonvolatile, reconfigurable interconnect programming. Maximum core utilization is possible for virtually any design.

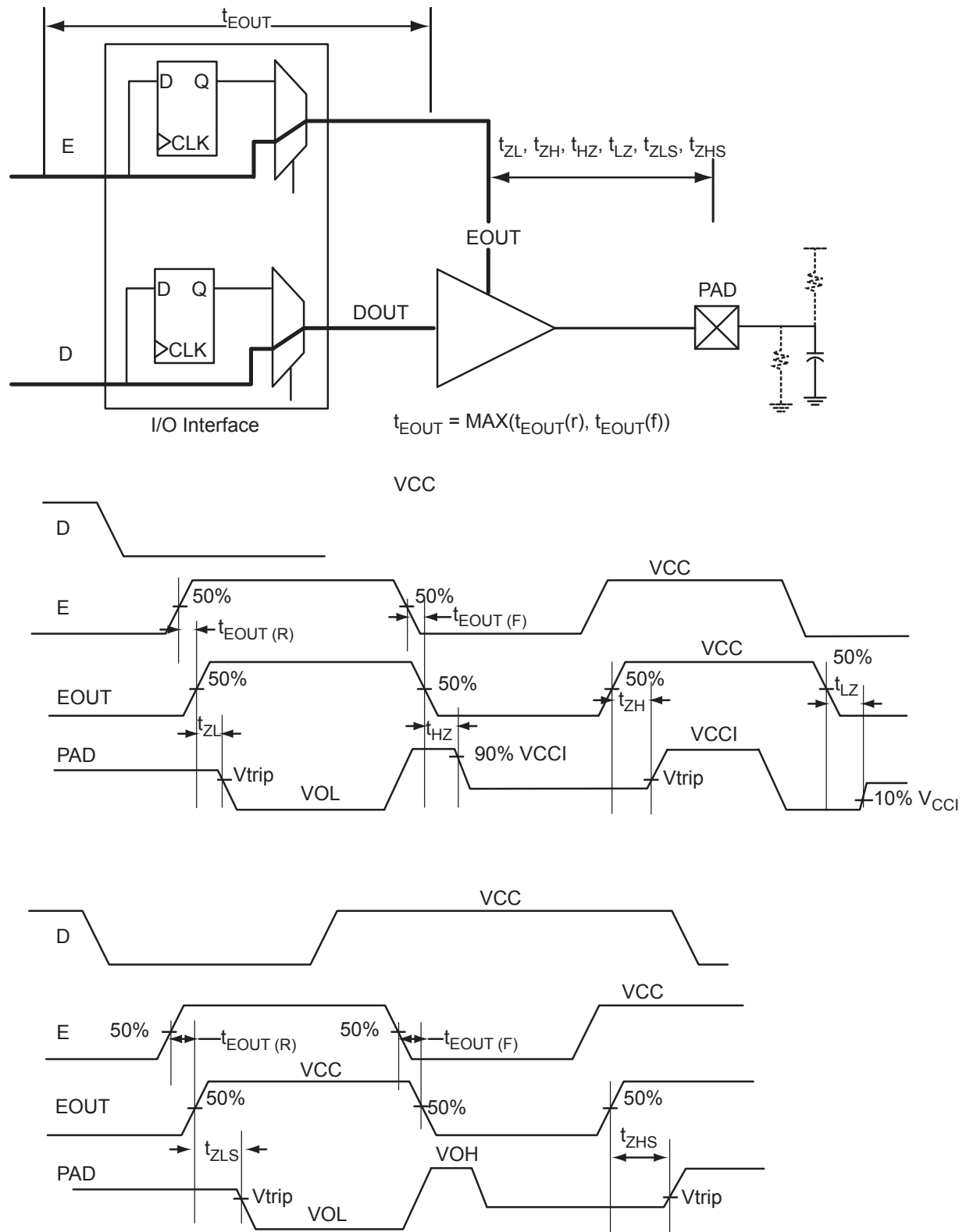


Figure 2-6 • Tristate Output Buffer Timing Model and Delays (example)

**Table 2-22 • Summary of Maximum and Minimum DC Input Levels
Applicable to Commercial and Industrial Conditions**

DC I/O Standards	Commercial ¹		Industrial ²	
	IIL ³	IIH ⁴	IIL ³	IIH ⁴
	μA	μA	μA	μA
3.3 V LVTTTL / 3.3 V LVCMOS	10	10	15	15
3.3 V LVCMOS Wide Range	10	10	15	15
2.5 V LVCMOS	10	10	15	15
1.8 V LVCMOS	10	10	15	15
1.5 V LVCMOS	10	10	15	15
1.2 V LVCMOS ⁵	10	10	15	15
1.2 V LVCOMS Wide Range ⁵	10	10	15	15
3.3 V PCI	10	10	15	15
3.3 V PCI-X	10	10	15	15
3.3 V GTL	10	10	15	15
2.5 V GTL	10	10	15	15
3.3 V GTL+	10	10	15	15
2.5 V GTL+	10	10	15	15
HSTL (I)	10	10	15	15
HSTL (II)	10	10	15	15
SSTL2 (I)	10	10	15	15
SSTL2 (II)	10	10	15	15
SSTL3 (I)	10	10	15	15
SSTL3 (II)	10	10	15	15

Notes:

1. Commercial range ($0^{\circ}\text{C} < T_A < 70^{\circ}\text{C}$)
2. Industrial range ($-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$)
3. IIL is the input leakage current per I/O pin over recommended operation conditions where $-0.3\text{ V} < V_{IN} < V_{IL}$.
4. IIH is the input leakage current per I/O pin over recommended operating conditions $V_{IH} < V_{IN} < V_{CCI}$. Input current is larger when operating outside recommended ranges.
5. Applicable to V2 devices operating at $V_{CCI} \geq V_{CC}$.

Summary of I/O Timing Characteristics – Default I/O Software Settings

Table 2-23 • Summary of AC Measuring Points

Standard	Input Reference Voltage (VREF_TYP)	Board Termination Voltage (VTT_REF)	Measuring Trip Point (Vtrip)
3.3 V LVTTTL / 3.3 V LVCMOS	–	–	1.4 V
3.3 V LVCMOS Wide Range	–	–	1.4 V
2.5 V LVCMOS	–	–	1.2 V
1.8 V LVCMOS	–	–	0.90 V
1.5 V LVCMOS	–	–	0.75 V
1.2 V LVCMOS*	–	–	0.6 V
1.2 V LVCMOS – Wide Range*	–	–	0.6 V
3.3 V PCI	–	–	0.285 * VCCI (RR)
	–	–	0.615 * VCCI (FF))
3.3 V PCI-X	–	–	0.285 * VCCI (RR)
	–	–	0.615 * VCCI (FF)
3.3 V GTL	0.8 V	1.2 V	VREF
2.5 V GTL	0.8 V	1.2 V	VREF
3.3 V GTL+	1.0 V	1.5 V	VREF
2.5 V GTL+	1.0 V	1.5 V	VREF
HSTL (I)	0.75 V	0.75 V	VREF
HSTL (II)	0.75 V	0.75 V	VREF
SSTL2 (I)	1.25 V	1.25 V	VREF
SSTL2 (II)	1.25 V	1.25 V	VREF
SSTL3 (I)	1.5 V	1.485 V	VREF
SSTL3 (II)	1.5 V	1.485 V	VREF
LVDS	–	–	Cross point
LVPECL	–	–	Cross point

Note: *Applicable to V2 devices ONLY operating in the 1.2 V core range.

Table 2-26 • Summary of I/O Timing Characteristics—Software Default Settings
Std. Speed Grade, Commercial-Case Conditions: $T_J = 70^\circ\text{C}$, Worst-Case $V_{CC} = 1.14\text{ V}$,
Worst-Case V_{CCI} (per standard)

I/O Standard	Drive Strength (mA)	Equivalent Software Default Drive Strength Option ¹ (mA)	Slew Rate	Capacitive Load (pF)	External Resistor (Ω)	t_{POUT} (ns)	t_{PP} (ns)	t_{PIN} (ns)	t_{PV} (ns)	t_{PYS} (ns)	t_{EOUT} (ns)	t_{ZL} (ns)	t_{ZH} (ns)	t_{LZ} (ns)	t_{HZ} (ns)	t_{ZLS} (ns)	t_{ZHS} (ns)	Units
3.3 V LVTTTL / 3.3 V LVCMOS	12	12	High	5	—	1.55	2.47	0.26	1.31	1.58	1.10	2.51	2.04	3.28	3.97	8.29	7.82	ns
3.3 V LVCMOS Wide Range ^{1,2}	100 μA	12	High	35	—	1.55	3.40	0.26	1.66	2.14	1.10	3.40	2.68	4.55	5.49	9.19	8.46	ns
2.5 V LVCMOS	12	12	High	5	—	1.55	2.51	0.26	1.55	1.77	1.10	2.54	2.22	3.36	3.85	8.33	8.00	ns
1.8 V LVCMOS	12	12	High	5	—	1.55	2.75	0.26	1.53	1.96	1.10	2.78	2.40	3.68	4.56	8.57	8.19	ns
1.5 V LVCMOS	12	12	High	5	—	1.55	3.10	0.26	1.72	2.16	1.10	3.15	2.70	3.86	4.68	8.93	8.49	ns
1.2 V LVCMOS	2	2	High	5	—	1.55	4.06	0.26	2.09	2.95	1.10	3.92	3.46	4.01	3.79	9.71	9.24	ns
1.2 V LVCMOS Wide Range ^{1,3}	100 μA	2	High	5	—	1.55	4.06	0.26	2.09	2.95	1.10	3.92	3.46	4.01	3.79	9.71	9.24	ns
3.3 V PCI	Per PCI spec	—	High	10	25 ⁴	1.55	2.76	0.26	1.19	1.63	1.10	2.79	2.16	3.29	3.97	8.58	7.94	ns
3.3 V PCI-X	Per PCI-X spec	—	High	10	25 ⁴	1.55	2.76	0.25	1.22	1.58	1.10	2.79	2.16	3.29	3.97	8.58	7.94	ns
3.3 V GTL	20 ⁵	—	High	10	25	1.55	2.08	0.25	2.76	—	1.10	2.09	2.08	—	—	7.88	7.87	ns
2.5 V GTL	20 ⁵	—	High	10	25	1.55	2.17	0.25	2.35	—	1.10	2.20	2.13	—	—	7.99	7.91	ns
3.3 V GTL+	35	—	High	10	25	1.55	2.12	0.25	1.62	—	1.10	2.14	2.07	—	—	7.93	7.85	ns
2.5 V GTL+	33	—	High	10	25	1.55	2.25	0.25	1.55	—	1.10	2.27	2.10	—	—	8.06	7.89	ns
HSTL (I)	8	—	High	20	50	1.55	3.09	0.25	1.95	—	1.10	3.11	3.09	—	—	8.90	8.88	ns
HSTL (II)	15	—	High	20	25	1.55	2.94	0.25	1.95	—	1.10	2.98	2.74	—	—	8.77	8.53	ns
SSTL2 (I)	15	—	High	30	50	1.55	2.18	0.25	1.40	—	1.10	2.21	2.03	—	—	7.99	7.82	ns
SSTL2 (II)	18	—	High	30	25	1.55	2.21	0.25	1.40	—	1.10	2.24	1.97	—	—	8.03	7.76	ns
SSTL3 (I)	14	—	High	30	50	1.55	2.33	0.25	1.33	—	1.10	2.36	2.02	—	—	8.15	7.81	ns
SSTL3 (II)	21	—	High	30	25	1.55	2.13	0.25	1.33	—	1.10	2.16	1.89	—	—	7.94	7.67	ns

Notes:

1. The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is $\pm 100\text{ }\mu\text{A}$. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.
3. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V wide range as specified in the JESD8-12 specification.
4. Resistance is used to measure I/O propagation delays as defined in PCI specifications. See [Figure 2-12 on page 2-49](#) for connectivity. This resistor is not required during normal operation.
5. Output drive strength is below JEDEC specification.
6. For specific junction temperature and voltage supply levels, refer to [Table 2-7 on page 2-6](#) for derating values.

3.3 V PCI, 3.3 V PCI-X

Peripheral Component Interface for 3.3 V standard specifies support for 33 MHz and 66 MHz PCI Bus applications.

Table 2-69 • Minimum and Maximum DC Input and Output Levels

3.3 V PCI/PCI-X	VIL		VIH		VOL	VOH	IOL	IOH	IOSH	IOSL	IIL ¹	IIH ²
Drive Strength	Min. V	Max. V	Min., V	Max. V	Max. V	Min. V	mA	mA	Max. mA ³	Max. mA ³	μA ⁴	μA ⁴
Per PCI specification	Per PCI curves										10	10

Notes:

1. IIL is the input leakage current per I/O pin over recommended operation conditions where $-0.3\text{ V} < V_{IN} < V_{IL}$.
2. IIH is the input leakage current per I/O pin over recommended operating conditions $V_{IH} < V_{IN} < V_{CCI}$. Input current is larger when operating outside recommended ranges.
3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
4. Currents are measured at 85°C junction temperature.

AC loadings are defined per the PCI/PCI-X specifications for the datapath; Microsemi loadings for enable path characterization are described in [Figure 2-12](#).

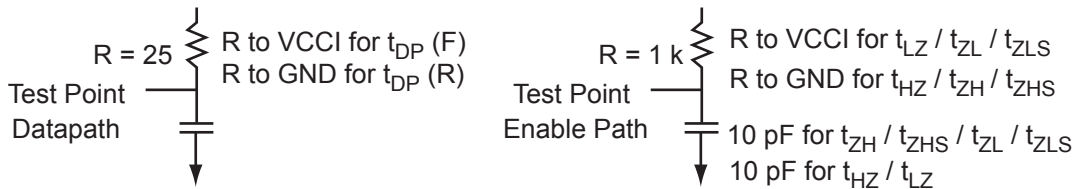


Figure 2-12 • AC Loading

AC loadings are defined per PCI/PCI-X specifications for the datapath; Microsemi loading for tristate is described in [Table 2-70](#).

Table 2-70 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C _{LOAD} (pF)
0	3.3	0.285 * VCCI for t _{DP(R)} 0.615 * VCCI for t _{DP(F)}	–	10

Note: *Measuring point = V_{trip}. See [Table 2-23 on page 2-23](#) for a complete table of trip points.

Voltage-Referenced I/O Characteristics

3.3 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 3.3 V.

Table 2-73 • Minimum and Maximum DC Input and Output Levels

3.3 V GTL	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL ¹	IIH ²
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max V	Min. V	mA	mA	Max. mA ³	Max. mA ³	μA ⁴	μA ⁴
20 mA ⁵	−0.3	VREF − 0.05	VREF + 0.05	3.6	0.4	−	20	20	268	181	10	10

Notes:

1. IIL is the input leakage current per I/O pin over recommended operating conditions where $-0.3\text{ V} < V_{IN} < V_{IL}$.
2. IIH is the input leakage current per I/O pin over recommended operating conditions $V_{IH} < V_{IN} < V_{CCI}$. Input current is larger when operating outside recommended ranges.
3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
4. Currents are measured at 85°C junction temperature.
5. Output drive strength is below JEDEC specification.

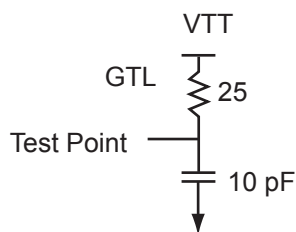


Figure 2-13 • AC Loading

Table 2-74 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C _{LOAD} (pF)
VREF − 0.05	VREF + 0.05	0.8	0.8	1.2	10

Note: *Measuring point = Vtrip. See Table 2-23 on page 2-23 for a complete table of trip points.

Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Clear

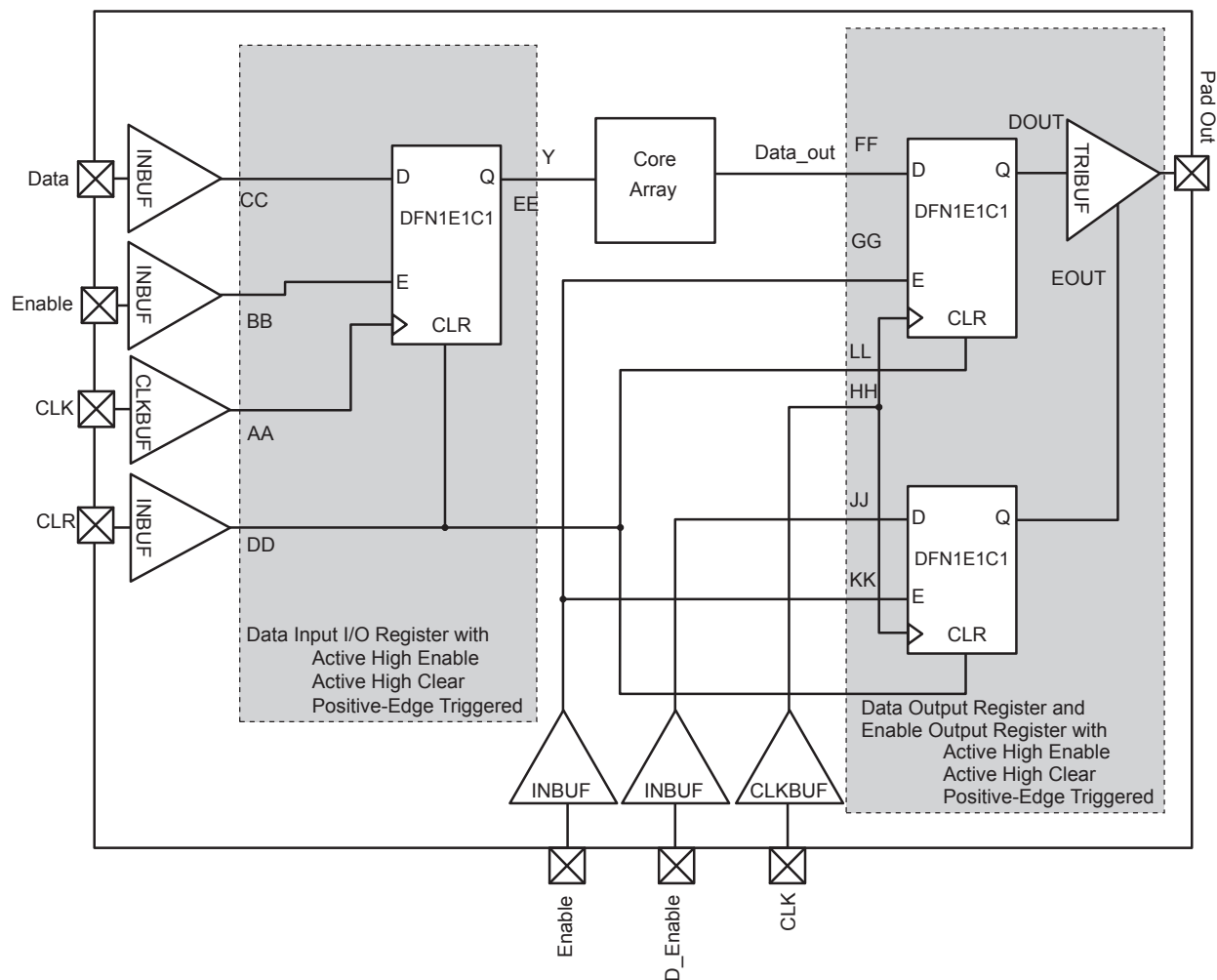


Figure 2-27 • Timing Model of the Registered I/O Buffers with Synchronous Enable and Asynchronous Clear

1.2 V DC Core Voltage

Table 2-128 • Output Enable Register Propagation Delays
Commercial-Case Conditions: $T_J = 70^{\circ}\text{C}$, Worst-Case $V_{CC} = 1.14\text{ V}$

Parameter	Description	Std.	Units
t_{OECLKQ}	Clock-to-Q of the Output Enable Register	1.10	ns
t_{OESUD}	Data Setup Time for the Output Enable Register	1.15	ns
t_{OEHD}	Data Hold Time for the Output Enable Register	0.00	ns
t_{OESUE}	Enable Setup Time for the Output Enable Register	1.22	ns
t_{OEHE}	Enable Hold Time for the Output Enable Register	0.00	ns
$t_{OECLR2Q}$	Asynchronous Clear-to-Q of the Output Enable Register	1.65	ns
$t_{OEPRE2Q}$	Asynchronous Preset-to-Q of the Output Enable Register	1.65	ns
$t_{OEREMCLR}$	Asynchronous Clear Removal Time for the Output Enable Register	0.00	ns
$t_{OERECCLR}$	Asynchronous Clear Recovery Time for the Output Enable Register	0.24	ns
$t_{OEREMPRE}$	Asynchronous Preset Removal Time for the Output Enable Register	0.00	ns
$t_{OERECPRE}$	Asynchronous Preset Recovery Time for the Output Enable Register	0.24	ns
$t_{OEWCCLR}$	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.19	ns
$t_{OEWPRES}$	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.19	ns
$t_{OECKMPWH}$	Clock Minimum Pulse Width HIGH for the Output Enable Register	0.31	ns
$t_{OECKMPWL}$	Clock Minimum Pulse Width LOW for the Output Enable Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to [Table 2-7 on page 2-6](#) for derating values.

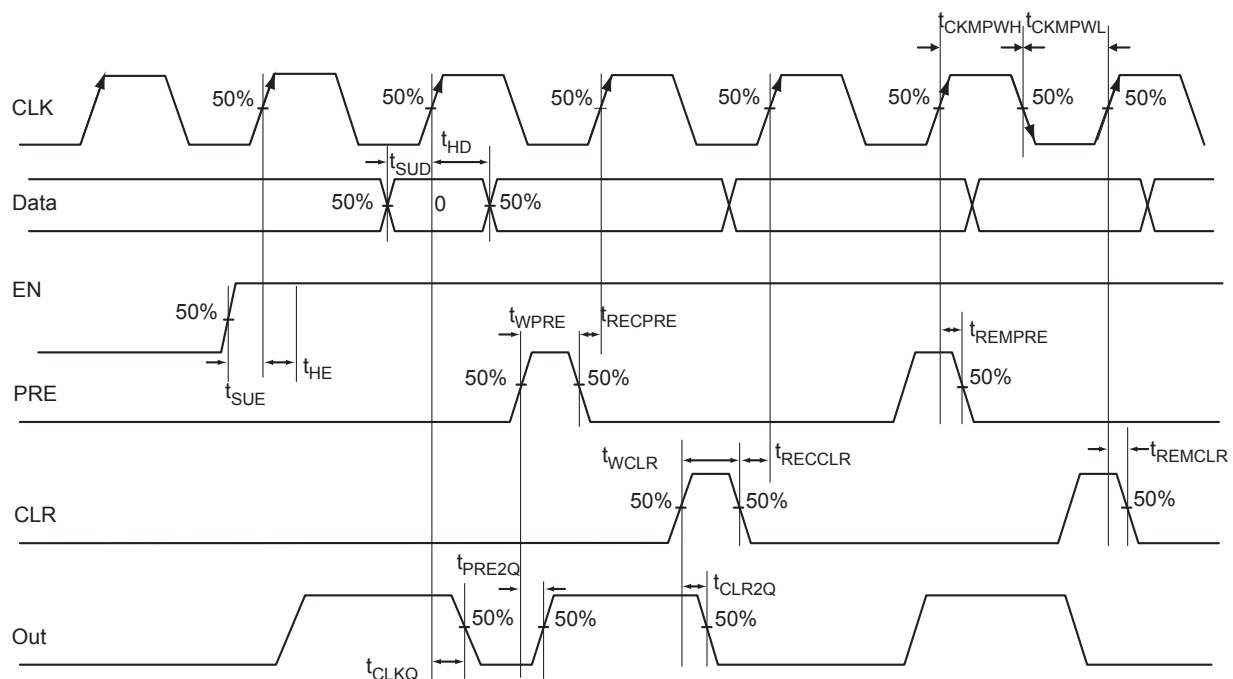


Figure 2-38 • Timing Model and Waveforms

Timing Characteristics

1.5 V DC Core Voltage

Table 2-137 • Register Delays

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t _{CLKQ}	Clock-to-Q of the Core Register	0.89	ns
t _{SUD}	Data Setup Time for the Core Register	0.81	ns
t _{HD}	Data Hold Time for the Core Register	0.00	ns
t _{SUE}	Enable Setup Time for the Core Register	0.73	ns
t _{HE}	Enable Hold Time for the Core Register	0.00	ns
t _{CLR2Q}	Asynchronous Clear-to-Q of the Core Register	0.60	ns
t _{PRE2Q}	Asynchronous Preset-to-Q of the Core Register	0.62	ns
t _{REMCLR}	Asynchronous Clear Removal Time for the Core Register	0.00	ns
t _{RECCLR}	Asynchronous Clear Recovery Time for the Core Register	0.24	ns
t _{REMPRE}	Asynchronous Preset Removal Time for the Core Register	0.00	ns
t _{RECPRE}	Asynchronous Preset Recovery Time for the Core Register	0.23	ns
t _{WCLR}	Asynchronous Clear Minimum Pulse Width for the Core Register	0.30	ns
t _{WPRE}	Asynchronous Preset Minimum Pulse Width for the Core Register	0.30	ns
t _{CKMPWH}	Clock Minimum Pulse Width HIGH for the Core Register	0.56	ns
t _{CKMPWL}	Clock Minimum Pulse Width LOW for the Core Register	0.56	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Global Tree Timing Characteristics

Global clock delays include the central rib delay, the spine delay, and the row delay. Delays do not include I/O input buffer clock delays, as these are I/O standard-dependent, and the clock may be driven and conditioned internally by the CCC module. For more details on clock conditioning capabilities, refer to the "Clock Conditioning Circuits" section on page 2-91. Table 2-139 and Table 2-141 present minimum and maximum global clock delays within the device. Minimum and maximum delays are measured with minimum and maximum loading.

Timing Characteristics

1.5 V DC Core Voltage

Table 2-139 • AGLE600 Global Resource
Commercial-Case Conditions: $T_J = 70^{\circ}\text{C}$, $V_{CC} = 1.425\text{ V}$

Parameter	Description	Std.		Units
		Min. ¹	Max. ²	
t_{RCKL}	Input Low Delay for Global Clock	1.48	1.82	ns
t_{RCKH}	Input High Delay for Global Clock	1.52	1.94	ns
t_{RCKMPWH}	Minimum Pulse Width High for Global Clock	1.18		ns
t_{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1.15		ns
t_{RCKSW}	Maximum Skew for Global Clock		0.42	ns

Notes:

1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-140 • AGLE3000 Global Resource
Commercial-Case Conditions: $T_J = 70^{\circ}\text{C}$, $V_{CC} = 1.425\text{ V}$

Parameter	Description	Std.		Units
		Min. ¹	Max. ²	
t_{RCKL}	Input Low Delay for Global Clock	2.00	2.34	ns
t_{RCKH}	Input High Delay for Global Clock	2.09	2.51	ns
t_{RCKMPWH}	Minimum Pulse Width High for Global Clock	1.18		ns
t_{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1.15		ns
t_{RCKSW}	Maximum Skew for Global Clock		0.42	ns

Notes:

1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

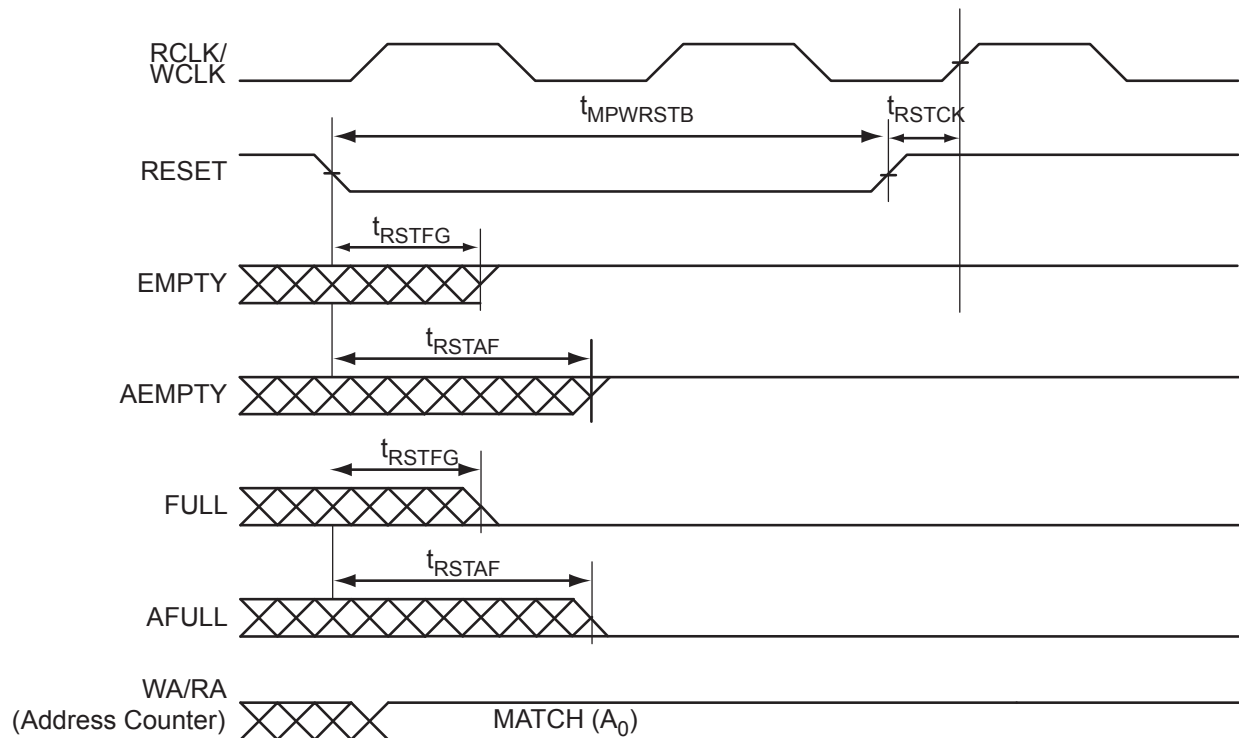


Figure 2-50 • FIFO Reset

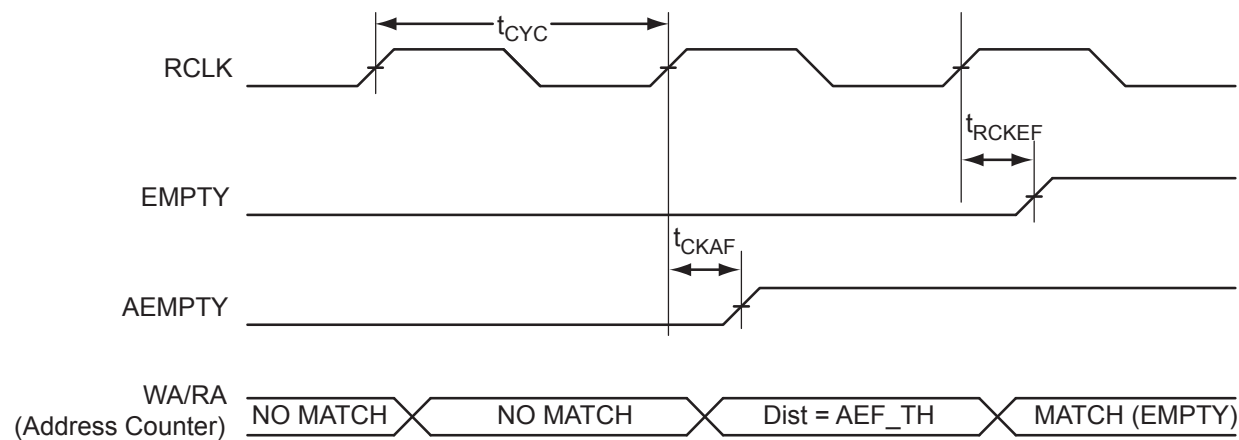


Figure 2-51 • FIFO EMPTY Flag and AEMPTY Flag Assertion

Timing Characteristics

Applies to 1.5 V DC Core Voltage

Table 2-149 • FIFO

Commercial-Case Conditions: $T_J = 70^{\circ}\text{C}$, $V_{CC} = 1.425\text{ V}$

Parameter	Description	Std.	Units
t_{ENS}	REN, WEN Setup Time	1.99	ns
t_{ENH}	REN, WEN Hold Time	0.16	ns
t_{BKS}	BLK Setup Time	0.30	ns
t_{BKH}	BLK Hold Time	0.00	ns
t_{DS}	Input Data (WD) Setup Time	0.76	ns
t_{DH}	Input Data (WD) Hold Time	0.25	ns
t_{CKQ1}	Clock HIGH to New Data Valid on RD (pass-through)	3.33	ns
t_{CKQ2}	Clock HIGH to New Data Valid on RD (pipelined)	1.80	ns
t_{RCKEF}	RCLK HIGH to Empty Flag Valid	3.53	ns
t_{WCKFF}	WCLK HIGH to Full Flag Valid	3.35	ns
t_{CKAF}	Clock HIGH to Almost Empty/Full Flag Valid	12.85	ns
t_{RSTFG}	RESET LOW to Empty/Full Flag Valid	3.48	ns
t_{RSTAF}	RESET LOW to Almost Empty/Full Flag Valid	12.72	ns
t_{RSTBQ}	RESET LOW to Data Out LOW on RD (pass-through)	2.02	ns
	RESET LOW to Data Out LOW on RD (pipelined)	2.02	ns
$t_{REMRSTB}$	RESET Removal	0.61	ns
$t_{RECRSTB}$	RESET Recovery	3.21	ns
$t_{MPWRSTB}$	RESET Minimum Pulse Width	0.68	ns
t_{CYC}	Clock Cycle Time	6.24	ns
F_{MAX}	Maximum Frequency	160	MHz

Note: For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

FG256		FG256		FG256	
Pin Number	AGLE600 Function	Pin Number	AGLE600 Function	Pin Number	AGLE600 Function
A1	GND	C5	GAC0/IO02NDB0V0	E9	IO21NDB1V0
A2	GAA0/IO00NDB0V0	C6	GAC1/IO02PDB0V0	E10	VCCIB1
A3	GAA1/IO00PDB0V0	C7	IO15NDB0V2	E11	VCCIB1
A4	GAB0/IO01NDB0V0	C8	IO15PDB0V2	E12	VMV1
A5	IO05PDB0V0	C9	IO20PDB1V0	E13	GBC2/IO38PDB2V0
A6	IO10PDB0V1	C10	IO25NDB1V0	E14	IO37NDB2V0
A7	IO12PDB0V2	C11	IO27PDB1V0	E15	IO41NDB2V0
A8	IO16NDB0V2	C12	GBC0/IO33NDB1V1	E16	IO41PDB2V0
A9	IO23NDB1V0	C13	VCCPLB	F1	IO124PDB7V0
A10	IO23PDB1V0	C14	VMV2	F2	IO125PDB7V0
A11	IO28NDB1V1	C15	IO36NDB2V0	F3	IO126PDB7V0
A12	IO28PDB1V1	C16	IO42PDB2V0	F4	IO130NDB7V1
A13	GBB1/IO34PDB1V1	D1	IO128PDB7V1	F5	VCCIB7
A14	GBA0/IO35NDB1V1	D2	IO129PDB7V1	F6	GND
A15	GBA1/IO35PDB1V1	D3	GAC2/IO132PDB7V1	F7	VCC
A16	GND	D4	VCOMPLA	F8	VCC
B1	GAB2/IO133PDB7V1	D5	GNDQ	F9	VCC
B2	GAA2/IO134PDB7V1	D6	IO09NDB0V1	F10	VCC
B3	GNDQ	D7	IO09PDB0V1	F11	GND
B4	GAB1/IO01PDB0V0	D8	IO13PDB0V2	F12	VCCIB2
B5	IO05NDB0V0	D9	IO21PDB1V0	F13	IO38NDB2V0
B6	IO10NDB0V1	D10	IO25PDB1V0	F14	IO40NDB2V0
B7	IO12NDB0V2	D11	IO27NDB1V0	F15	IO40PDB2V0
B8	IO16PDB0V2	D12	GNDQ	F16	IO45PSB2V1
B9	IO20NDB1V0	D13	VCOMPLB	G1	IO124NDB7V0
B10	IO24NDB1V0	D14	GBB2/IO37PDB2V0	G2	IO125NDB7V0
B11	IO24PDB1V0	D15	IO39PDB2V0	G3	IO126NDB7V0
B12	GBC1/IO33PDB1V1	D16	IO39NDB2V0	G4	GFC1/IO120PPB7V0
B13	GBB0/IO34NDB1V1	E1	IO128NDB7V1	G5	VCCIB7
B14	GNDQ	E2	IO129NDB7V1	G6	VCC
B15	GBA2/IO36PDB2V0	E3	IO132NDB7V1	G7	GND
B16	IO42NDB2V0	E4	IO130PDB7V1	G8	GND
C1	IO133NDB7V1	E5	VMV0	G9	GND
C2	IO134NDB7V1	E6	VCCIB0	G10	GND
C3	VMV7	E7	VCCIB0	G11	VCC
C4	VCCPLA	E8	IO13NDB0V2	G12	VCCIB2

FG256	
Pin Number	AGLE600 Function
P9	IO82PDB5V0
P10	IO76NDB4V1
P11	IO76PDB4V1
P12	VMV4
P13	TCK
P14	VPUMP
P15	TRST
P16	GDA0/IO67NDB3V1
R1	GEA1/IO102PDB6V0
R2	GEA0/IO102NDB6V0
R3	GNDQ
R4	GEC2/IO99PDB5V2
R5	IO95NPB5V1
R6	IO91NDB5V1
R7	IO91PDB5V1
R8	IO83NDB5V0
R9	IO83PDB5V0
R10	IO77NDB4V1
R11	IO77PDB4V1
R12	IO69NDB4V0
R13	GDB2/IO69PDB4V0
R14	TDI
R15	GNDQ
R16	TDO
T1	GND
T2	IO100NDB5V2
T3	FF/GEB2/IO100PDB5 V2
T4	IO99NDB5V2
T5	IO88NDB5V0
T6	IO88PDB5V0
T7	IO89NSB5V0
T8	IO80NSB4V1
T9	IO81NDB4V1
T10	IO81PDB4V1
T11	IO70NDB4V0

FG256	
Pin Number	AGLE600 Function
T12	GDC2/IO70PDB4V0
T13	IO68NDB4V0
T14	GDA2/IO68PDB4V0
T15	TMS
T16	GND

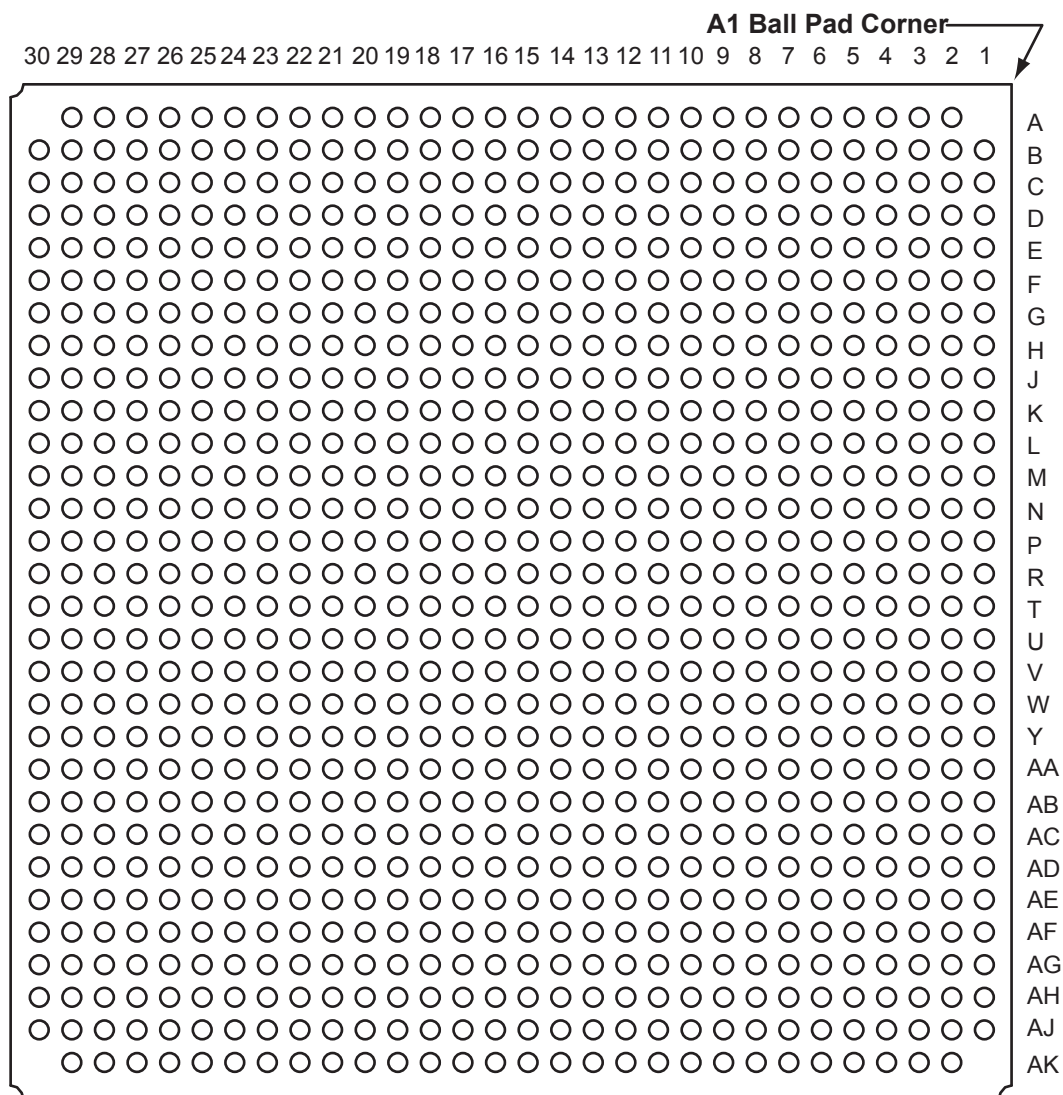
FG484		FG484		FG484	
Pin Number	AGLE600 Function	Pin Number	AGLE600 Function	Pin Number	AGLE600 Function
C18	GND	E9	IO10NDB0V1	F22	NC
C19	NC	E10	IO12NDB0V2	G1	IO127NDB7V1
C20	NC	E11	IO16PDB0V2	G2	IO127PDB7V1
C21	NC	E12	IO20NDB1V0	G3	NC
C22	VCCIB2	E13	IO24NDB1V0	G4	IO128PDB7V1
D1	NC	E14	IO24PDB1V0	G5	IO129PDB7V1
D2	NC	E15	GBC1/IO33PDB1V1	G6	GAC2/IO132PDB7V1
D3	NC	E16	GBB0/IO34NDB1V1	G7	VCOMPLA
D4	GND	E17	GNDQ	G8	GNDQ
D5	GAA0/IO00NDB0V0	E18	GBA2/IO36PDB2V0	G9	IO09NDB0V1
D6	GAA1/IO00PDB0V0	E19	IO42NDB2V0	G10	IO09PDB0V1
D7	GAB0/IO01NDB0V0	E20	GND	G11	IO13PDB0V2
D8	IO05PDB0V0	E21	NC	G12	IO21PDB1V0
D9	IO10PDB0V1	E22	NC	G13	IO25PDB1V0
D10	IO12PDB0V2	F1	NC	G14	IO27NDB1V0
D11	IO16NDB0V2	F2	IO131NDB7V1	G15	GNDQ
D12	IO23NDB1V0	F3	IO131PDB7V1	G16	VCOMPLB
D13	IO23PDB1V0	F4	IO133NDB7V1	G17	GBB2/IO37PDB2V0
D14	IO28NDB1V1	F5	IO134NDB7V1	G18	IO39PDB2V0
D15	IO28PDB1V1	F6	VMV7	G19	IO39NDB2V0
D16	GBB1/IO34PDB1V1	F7	VCCPLA	G20	IO43PDB2V0
D17	GBA0/IO35NDB1V1	F8	GAC0/IO02NDB0V0	G21	IO43NDB2V0
D18	GBA1/IO35PDB1V1	F9	GAC1/IO02PDB0V0	G22	NC
D19	GND	F10	IO15NDB0V2	H1	NC
D20	NC	F11	IO15PDB0V2	H2	NC
D21	NC	F12	IO20PDB1V0	H3	VCC
D22	NC	F13	IO25NDB1V0	H4	IO128NDB7V1
E1	NC	F14	IO27PDB1V0	H5	IO129NDB7V1
E2	NC	F15	GBC0/IO33NDB1V1	H6	IO132NDB7V1
E3	GND	F16	VCCPLB	H7	IO130PDB7V1
E4	GAB2/IO133PDB7V1	F17	VMV2	H8	VMV0
E5	GAA2/IO134PDB7V1	F18	IO36NDB2V0	H9	VCCIB0
E6	GNDQ	F19	IO42PDB2V0	H10	VCCIB0
E7	GAB1/IO01PDB0V0	F20	NC	H11	IO13NDB0V2
E8	IO05NDB0V0	F21	NC	H12	IO21NDB1V0

FG484	
Pin Number	AGLE3000 Function
H13	VCCIB1
H14	VCCIB1
H15	VMV1
H16	GBC2/IO84PDB2V0
H17	IO83NDB2V0
H18	IO100NDB2V2
H19	IO100PDB2V2
H20	VCC
H21	VMV2
H22	IO105PDB2V2
J1	IO285NDB7V1
J2	IO285PDB7V1
J3	VMV7
J4	IO279PDB7V0
J5	IO283PDB7V1
J6	IO281PDB7V0
J7	IO287NDB7V1
J8	VCCIB7
J9	GND
J10	VCC
J11	VCC
J12	VCC
J13	VCC
J14	GND
J15	VCCIB2
J16	IO84NDB2V0
J17	IO104NDB2V2
J18	IO104PDB2V2
J19	IO106PPB2V3
J20	GNDQ
J21	IO109PDB2V3
J22	IO107PDB2V3
K1	IO277NDB7V0
K2	IO277PDB7V0
K3	GNDQ

FG484	
Pin Number	AGLE3000 Function
K4	IO279NDB7V0
K5	IO283NDB7V1
K6	IO281NDB7V0
K7	GFC1/IO275PPB7V0
K8	VCCIB7
K9	VCC
K10	GND
K11	GND
K12	GND
K13	GND
K14	VCC
K15	VCCIB2
K16	GCC1/IO112PPB2V3
K17	IO108NDB2V3
K18	IO108PDB2V3
K19	IO110NPB2V3
K20	IO106NPB2V3
K21	IO109NDB2V3
K22	IO107NDB2V3
L1	IO257PSB6V2
L2	IO276PDB7V0
L3	IO276NDB7V0
L4	GFB0/IO274NPB7V0
L5	GFA0/IO273NDB6V4
L6	GFB1/IO274PPB7V0
L7	VCOMPLF
L8	GFC0/IO275NPB7V0
L9	VCC
L10	GND
L11	GND
L12	GND
L13	GND
L14	VCC
L15	GCC0/IO112NPB2V3
L16	GCB1/IO113PPB2V3

FG484	
Pin Number	AGLE3000 Function
L17	GCA0/IO114NPB3V0
L18	VCOMPLC
L19	GCB0/IO113NPB2V3
L20	IO110PPB2V3
L21	IO111NDB2V3
L22	IO111PDB2V3
M1	GNDQ
M2	IO255NPB6V2
M3	IO272NDB6V4
M4	GFA2/IO272PDB6V4
M5	GFA1/IO273PDB6V4
M6	VCCPLF
M7	IO271NDB6V4
M8	GFB2/IO271PDB6V4
M9	VCC
M10	GND
M11	GND
M12	GND
M13	GND
M14	VCC
M15	GCB2/IO116PPB3V0
M16	GCA1/IO114PPB3V0
M17	GCC2/IO117PPB3V0
M18	VCCPLC
M19	GCA2/IO115PDB3V0
M20	IO115NDB3V0
M21	IO126PDB3V1
M22	IO124PSB3V1
N1	IO255PPB6V2
N2	IO253NDB6V2
N3	VMV6
N4	GFC2/IO270PPB6V4
N5	IO261PPB6V3
N6	IO263PDB6V3
N7	IO263NDB6V3

FG896



Note: This is the bottom view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/docs.aspx>.

FG896	
Pin Number	AGLE3000 Function
AC18	IO182PPB4V3
AC19	IO170NPB4V2
AC20	IO164NDB4V1
AC21	IO164PDB4V1
AC22	IO162PPB4V1
AC23	GND
AC24	VCOMPLD
AC25	IO150NDB3V4
AC26	IO148NDB3V4
AC27	GDA1/IO153PDB3V4
AC28	IO145NDB3V3
AC29	IO143NDB3V3
AC30	IO137NDB3V2
AD1	GND
AD2	IO242NPB6V1
AD3	IO240NDB6V0
AD4	GEC0/IO236NDB6V0
AD5	VCCIB6
AD6	GNDQ
AD6	GNDQ
AD7	VCC
AD8	VMV5
AD9	VCCIB5
AD10	IO224PPB5V3
AD11	IO218NPB5V3
AD12	IO216PPB5V2
AD13	IO210PPB5V2
AD14	IO202PPB5V1
AD15	IO194PDB5V0
AD16	IO190PDB4V4
AD17	IO182NPB4V3
AD18	IO176NDB4V2
AD19	IO176PDB4V2
AD20	IO170PPB4V2
AD21	IO166PDB4V1

FG896	
Pin Number	AGLE3000 Function
AD22	VCCIB4
AD23	TCK
AD24	VCC
AD25	TRST
AD26	VCCIB3
AD27	GDA0/IO153NDB3V4
AD28	GDC0/IO151NDB3V4
AD29	GDC1/IO151PDB3V4
AD30	GND
AE1	IO242PPB6V1
AE2	VCC
AE3	IO239PDB6V0
AE4	IO239NDB6V0
AE5	VMV6
AE5	VMV6
AE6	GND
AE7	GNDQ
AE8	IO230NDB5V4
AE9	IO224NPB5V3
AE10	IO214NPB5V2
AE11	IO212NDB5V2
AE12	IO212PDB5V2
AE13	IO202NPB5V1
AE14	IO200NDB5V0
AE15	IO196PDB5V0
AE16	IO190NDB4V4
AE17	IO184PDB4V3
AE18	IO184NDB4V3
AE19	IO172PDB4V2
AE20	IO172NDB4V2
AE21	IO166NDB4V1
AE22	IO160PDB4V0
AE23	GNDQ
AE24	VMV4
AE25	GND

FG896	
Pin Number	AGLE3000 Function
AE26	GDB0/IO152NDB3V4
AE27	GDB1/IO152PDB3V4
AE28	VMV3
AE28	VMV3
AE29	VCC
AE30	IO149PDB3V4
AF1	GND
AF2	IO238PPB6V0
AF3	VCCIB6
AF4	IO220NPB5V3
AF5	VCC
AF6	IO228NDB5V4
AF7	VCCIB5
AF8	IO230PDB5V4
AF9	IO229NDB5V4
AF10	IO229PDB5V4
AF11	IO214PPB5V2
AF12	IO208NDB5V1
AF13	IO208PDB5V1
AF14	IO200PDB5V0
AF15	IO196NDB5V0
AF16	IO186NDB4V4
AF17	IO186PDB4V4
AF18	IO180NDB4V3
AF19	IO180PDB4V3
AF20	IO168NDB4V1
AF21	IO168PDB4V1
AF22	IO160NDB4V0
AF23	IO158NPB4V0
AF24	VCCIB4
AF25	IO154NPB4V0
AF26	VCC
AF27	TDO
AF28	VCCIB3
AF29	GNDQ

Datasheet Categories

Categories

In order to provide the latest information to designers, some datasheet parameters are published before data has been fully characterized from silicon devices. The data provided for a given device, as highlighted in the "IGLOOe Device Status" table, is designated as either "Product Brief," "Advance," "Preliminary," or "Production." The definitions of these categories are as follows:

Product Brief

The product brief is a summarized version of a datasheet (advance or production) and contains general product information. This document gives an overview of specific device and family information.

Advance

This version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production. This label only applies to the DC and Switching Characteristics chapter of the datasheet and will only be used when the data has not been fully characterized.

Preliminary

The datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.

Production

This version contains information that is considered to be final.

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